

# TFR2N,TFR2T

## Strobe Applications (Fast Recovery)

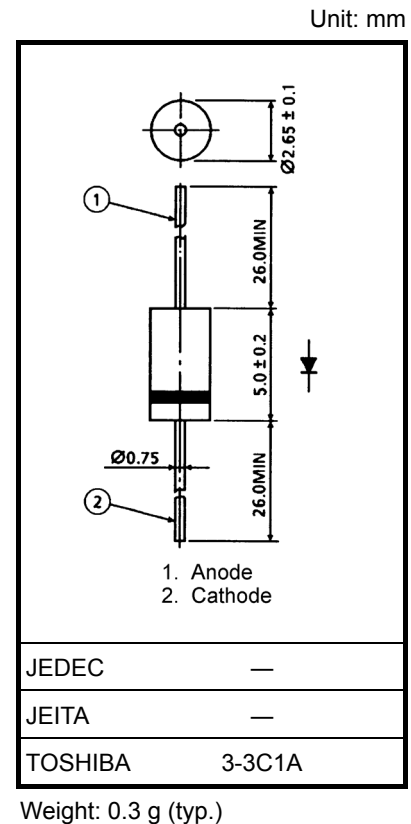
- Average forward current:  $I_F(AV) = 0.5$  A
- Repetitive peak reverse voltage:  $V_{RRM} = 1000, 1500$  V
- Reverse-recovery time:  $t_{rr} = 4$   $\mu$ s

## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Repetitive peak reverse voltage	TFR2N	$V_{RRM}$	V
	TFR2T		
Average forward current	$I_{F(AV)}$	0.5	A
$I^2t$ limit value ( $t = 1 \sim 10$ ms)	$I^2t$	2	$\text{A}^2\text{s}$
Peak one cycle surge forward current (non-repetitive)	$I_{FSM}$	20	A
Junction temperature	$T_j$	$-40 \sim 125$	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	$-40 \sim 125$	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

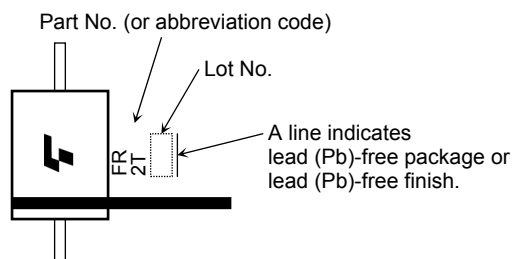
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



## Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Max	Unit
Peak forward voltage	$V_{FM}$	$I_{FM} = 0.5$ A	—	1.5	V
Repetitive peak reverse current	$I_{RRM}$	$V_{RRM} = \text{Rated}$	—	10	$\mu\text{A}$
Reverse recovery time	$t_{rr}$	$I_F = 20$ mA, $I_R = 1$ mA	—	4	$\mu\text{s}$

## Marking



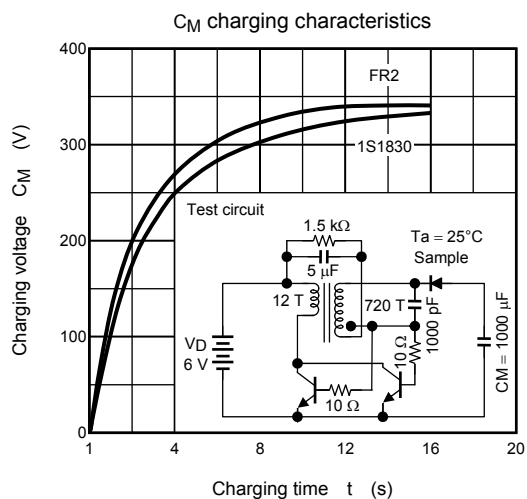
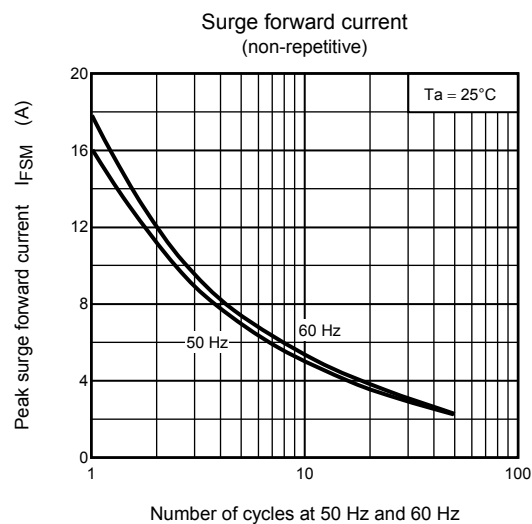
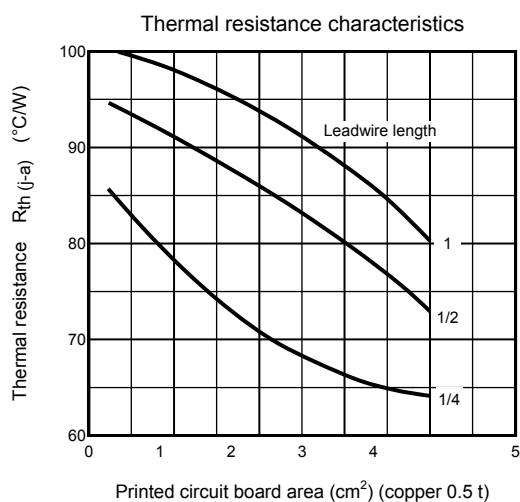
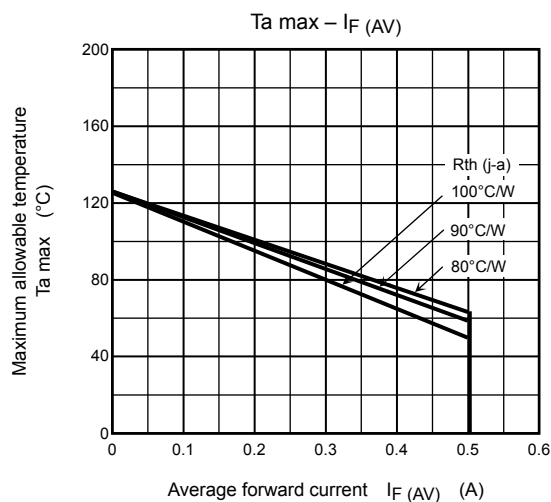
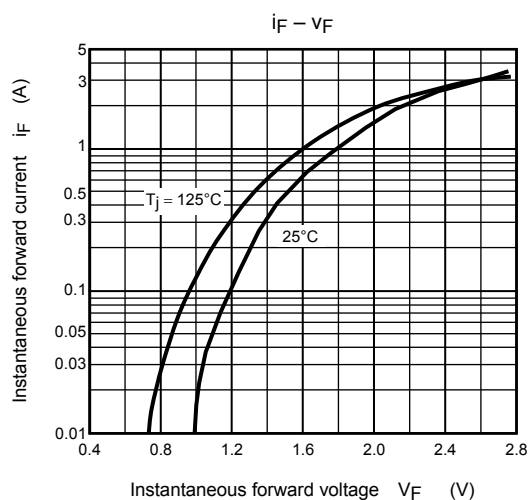
Abbreviation Code	Part No.
FR2N	TFR2N
FR2T	TFR2T

## Handling Precaution

The absolute maximum ratings denote the absolute maximum ratings, which are rated values and must not be exceeded during operation, even for an instant. The following are the general derating methods that we recommend when you design a circuit with a device.

- VRRM:** Because this device is developed for use in a strobe flash, we recommend that peak voltage of set's apply voltage that generates pulse be no greater than 80% of the absolute maximum rating of VRRM and DC supply voltage be no greater than 400 V. VRRM has a temperature coefficient of 0.1%/°C. Take this temperature coefficient into account designing a device at low temperature.
- IF(AV):** We recommend that the worst case current be no greater than 80% of the absolute maximum rating of IF(AV). Carry out adequate heat design. If you can't design a circuit with excellent heat radiation, set the margin by using an allowable Tamax-IF(AV) curve.
- IFSM:** This rating specifies the non-repetitive peak current in one cycle of a 50-Hz sine wave, condition angle 180. Therefore, this is only applied for an abnormal operation, which seldom occurs during the lifespan of the device.
- Tj:** We recommend that a device be used at a Tj of below 100°C under the worst load and heat radiation conditions.

Please refer to the Rectifiers databook for further information.



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